

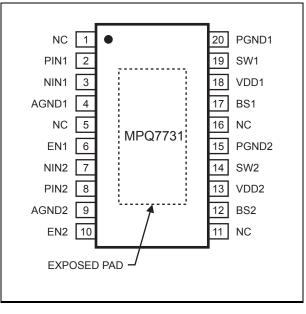
#### **ORDERING INFORMATION**

Part Number*	Package	Top Marking	Free Air Temperature (T <sub>A</sub> )	
MPQ7731DF	TSSOP20	MP7731DF	-40°C to +85°C	

\* For Tape & Reel, add suffix -Z (e.g. MPQ7731DF-Z).

For RoHS Compliant packaging, add suffix -LF (e.g. MPQ7731DF-LF-Z)

## PACKAGE REFERENCE



## ABSOLUTE MAXIMUM RATINGS (1)

Supply Voltage V <sub>DD</sub>	
BS Voltage	
Enable Voltage V <sub>EN</sub>	0.3V to 6V
$V_{SW}, V_{PIN}, V_{NIN}$	1V to V <sub>DD</sub> +1V
AGND to PGND	0.3V to 0.3V
Continuous Power Dissipa	ation (T <sub>A</sub> = +25°C) <sup>(2)</sup>
	3.1W
Junction Temperature	
Lead Temperature	
Storage Temperature	65°C to 150°C
	(3)

#### Recommended Operating Conditions <sup>(3)</sup>

# Thermal Resistance $\boldsymbol{\theta}_{JA}$ $\boldsymbol{\theta}_{JC}$ TSSOP20406

#### Notes:

- 1) Exceeding these ratings may damage the device.
- 2) The maximum allowable power dissipation is a function of the maximum junction temperature T<sub>J</sub> (MAX), the junction-toambient thermal resistance  $\theta_{JA}$ , and the ambient temperature T<sub>A</sub>. The maximum allowable continuous power dissipation at any ambient temperature is calculated by P<sub>D</sub> (MAX) = (T<sub>J</sub> (MAX)-T<sub>A</sub>)/ $\theta_{JA}$ . Exceeding the maximum allowable power dissipation will cause excessive die temperature, and the regulator will go into thermal shutdown. Internal thermal shutdown circuitry protects the device from permanent damage.
- The device is not guaranteed to function outside of its operating conditions.
- 4) Measured on JESD51-7, 4-layer PCB.



## ELECTRICAL CHARACTERISTICS <sup>(5, 6)</sup>

 $V_{DD}$  = 16.5V,  $V_{EN}$  = 5V,  $R_L$  = 4 $\Omega,$   $T_A$  = -40°C  $\,$  To +85°C, Typical values are at  $T_A$ =25°C , unless otherwise noted.

Parameter	Symbol	Symbol Condition		Min	Тур	Max	Units
Standby Current		$V_{EN} = 0V$			2	10	μA
Quiescent Current					3	6	mA
SW On Resistance		Sourcing and Sinking			0.18		Ω
Short Circuit Current		Sourcing and Sinking			5.0		А
PIN, NIN Input Common Mode Voltage Range				0	$V_{DD}/2$	V <sub>DD</sub> -1.5	V
PIN, NIN Input Current		V <sub>PIN</sub> =V <sub>NIN</sub> =8V			1	5	μA
EN Enable Threshold Voltage		V <sub>EN</sub> Rising			1.4	2.0	V
		V <sub>EN</sub> Falling		0.4	1.2		V
EN Enable Input Current		$V_{EN} = 5V$			1	5	μA
EN Enable Input Current		$V_{\text{EN}}$ Rising			1		μA
			T <sub>A</sub> = -40°C To +85°C		1	5	
Thermal Shutdown Trip Point		T <sub>J</sub> Rising			150		°C
Thermal Shutdown Hysteresis					30		°C



## **OPERATING SPECIFICATIONS**<sup>(7)</sup>

Circuit of Figure 1,  $V_{DD}$  = 16.5V,  $V_{EN}$  = 5V,  $R_L$  = 4 $\Omega$ ,  $T_A$  = +25°C, unless otherwise noted.

Parameter	Symbol	Condition	Min	Тур	Мах	Units
Standby Current		V <sub>EN</sub> = 0V		700		μA
Quiescent Current				28		mA
		f=1kHz, THD+N=10%		30		W
Power Output		f=1kHz, THD+N=10%, $R_L$ =8 $\Omega$		17		W
THD+ Noise		P <sub>OUT</sub> =1W, f=1kHz		0.2		%
		$P_{OUT}$ =1W, f=1kHz, R <sub>L</sub> =8 $\Omega$		0.1		%
Efficiency		f=1kHz, P <sub>OUT</sub> =10W		85		%
Efficiency		f=1kHz, $P_{OUT}$ =10W, $R_L$ =8 $\Omega$		88		%
Maximum Power Bandwidth				20		kHz
Dynamic Range				90		dB
Noise Floor		A-Weighted		370		μV
Power Supply Rejection		f=1kHz		60		dB

Note:

5) The device is not guaranteed to function outside its operating rating.

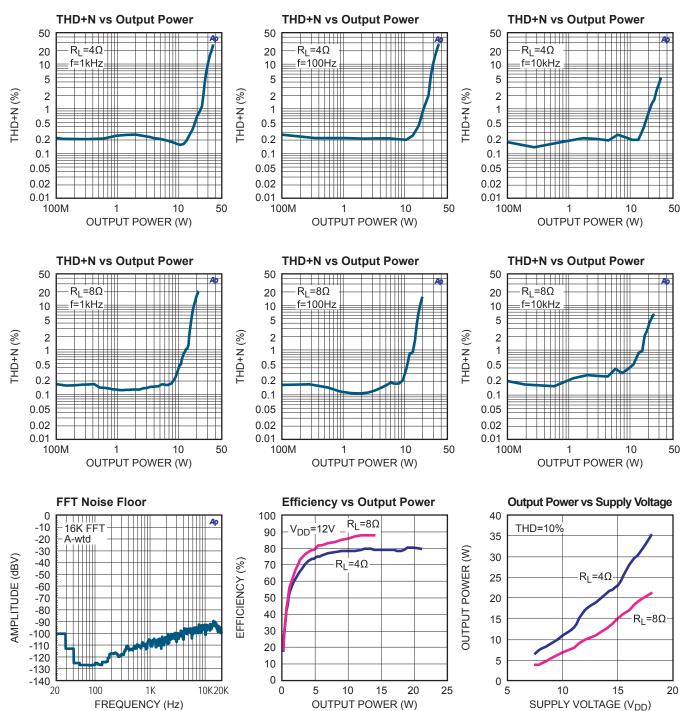
6) Electrical Characteristics are for the IC only with no external components except bypass capacitors.

7) Operating Specifications are for the IC in Typical Application circuit (Figure 1).



## **TYPICAL PERFORMANCE CHARACTERISTICS**

Circuit of Figure 1,  $V_{DD}$ =16.5V,  $T_A$ =25°C, unless otherwise noted.





### **PIN FUNCTIONS**

Pin #	Name	Description			
1, 5, 11, 16	NC	No Connect – Not internally connected			
2	PIN1	Amplifier 1 Positive Input. PIN1 is the positive side of the differential input to Amplifier 1 Use a resistive voltage divider to set the voltage at PIN1 to $V_{DD}/2$ . See Figure 1.			
3	NIN1	Amplifier 1 Negative Input. NIN1 is the negative side of the differential input to Amplifie 1. See Figure 1.			
4	AGND1	Analog Ground 1. Connect AGND1 to AGND2.			
6	EN1	Enable Input 1. EN1 must be connected to EN2. Drive high to enable MPQ7731, drive low to disable.			
7	NIN2	Amplifier 2 Negative Input. NIN2 is the negative side of the differential input to Amplifier 2. See Figure 1.			
8	PIN2	Amplifier 2 Positive Input. PIN2 is the positive side of the differential input to Amplifier 2. Use a resistive voltage divider to set the voltage at PIN2 to $V_{DD}/2$ . See Figure 1.			
9	AGND2	Analog Ground 2. Connect AGND2 to AGND1.			
10	EN2	Enable Input 2. EN2 must be connected to EN1. Drive high to enable MPQ7731, drive low to disable.			
12	BS2	High-Side MOSFET Bootstrap Input for Amplifier 2. A capacitor from BS2 to SW2 supplies the gate drive current to the internal high-side MOSFET. Connect a $1\mu$ F capacitor from SW2 to BS2. See Figure 1.			
13	VDD2	Power Supply Input. Bypass VDD2 to PGND2 with a 1µF X7R capacitor (in addition to the main bulk capacitor), placed close to the IC PIN13 and PIN15.			
14	SW2	Switched Power Output. SW2 is the output of Amplifier 2. Connect the LC filter to this pin. See Figure 1.			
15	PGND2	Power Ground for Amplifier 2. Connect PGND2 to PGND1. See Figure 1.			
17	BS1	High-Side MOSFET Bootstrap Input for Amplifier 1. A capacitor from BS1 to SW1 supplies the gate drive current to the internal high-side MOSFET. Connect a $1\mu$ F capacitor from SW1 to BS1. See Figure 1.			
18	VDD1	Power Supply Input. Bypass VDD1 to PGND1 with a 1µF X7R capacitor (in addition to the main bulk capacitor), placed close to the IC PIN18 and PIN20.			
19	SW1	Switched Power Output. SW1 is the output of Amplifier 1. Connect the LC filter to this pin. See Figure 1.			
20	PGND1	Power Ground for Amplifier 1. Connect PGND1 to PGND2. See Figure 1.			



## APPLICATION INFORMATION

#### **COMPONENT SELECTION**

The MPQ7731 uses a minimum number of external components to complete a fully bridged Class D audio amplifier. The circuit in Figure 1 shows a typical application. Use the following sections to customize the amplifier for your particular application.

#### Setting the Voltage Gain

The voltage gain sets the output voltage swing for a given input voltage swing and is set by the following equation:

$$A_{V} = 2\left(\frac{R_{1}}{R_{4}}\right)$$

Where:

- R1 = R8
- R4 = R6

The maximum output voltage swing is limited by the power supply. The MPQ7731 is a bridged amplifier and the output load is driven differentially. Each side of the load is limited to a maximum peak-to-peak voltage swing of approximately  $V_{DD}$ . To achieve the maximum output power of the MPQ7731 amplifier, set the amplifier gain such that the maximum peak-to-peak input signal results in at least the maximum peak-topeak output voltage swing.

#### **Setting the Switching Frequency**

The idle switching frequency (the switching frequency with no audio input signal) is a function of the supply voltage,  $V_{DD}$ , the capacitors C14, C6 and C10 and resistors R1 and R8. Lower switching frequencies result in more inductor ripple, causing more quiescent output voltage ripple, increasing the output noise.. Higher switching frequencies result in more power loss. The optimum quiescent switching frequency is approximately 400kHz-600kHz. C6 and C14 are typically 1pF to 2.2pF. C10 is used to program the idle switching frequency.

#### Choosing the LC Filter

Two identical LC filters are required in the typical application. The inductor-capacitor (LC) filter is a second order filter that converts the

pulse train at SW (Pins 14, 19) to the output differential signal that drives the speaker. Typical values for the LC filters are shown in Figure 1. The characteristic frequency of the LC filter needs to be high enough to allow high frequency audio to reach the output, yet needs to be low enough to filter out high frequency contents of the pulses from SW.

The characteristic frequency of the LC filter is:

$$f_0 = \frac{1}{2\pi\sqrt{LC}}$$

Where:

• L = L1 + L2, L1 = L2  
• C = C9 + 
$$\left(\frac{C2 \times C17}{C2 + C17}\right)$$
, C2 = C17

The quality factor (Q) of the LC filter is important. If this is too low, output noise will increase. If the Q factor is too high, then peaking may occur at high signal frequencies reducing the pass-band flatness.

The Q is calculated as:

$$Q = \frac{R}{\sqrt{\frac{L}{C}}}$$

Where R is the load (speaker) resistance.

Use an LC filter with a Q between 0.7 and 2.0. The actual output ripple and noise is greatly affected by the type of inductor and capacitor used in the LC filter. Use a film capacitor and an inductor with sufficient power handling capability to supply the output current to the load. The inductor should exhibit soft saturation characteristics. If the inductor exhibits hard saturation, it should operate well below the saturation current. Gapped ferrite, MPP, Powdered Iron, or similar type toroidal cores are recommended. If open or shielded bobbin ferrite cores are used, make sure that the start windings of each inductor line up (all starts going toward SW pin, or all starts going toward the output) to prevent crosstalk or other channel-to-channel interference.



#### **Input Coupling Capacitor**

The input coupling capacitors, C7 and C12, are used to pass only the AC audio signal to the input of the amplifier. In a typical system application, the source input signal is typically centered around the circuit ground, while the MPQ7731 input is at half the power supply voltage ( $V_{DD}/2$ ). The input coupling capacitor transmits the AC signal from the source to the MPQ7731 while blocking the DC voltage. This input coupling capacitor creates a low-pass filter with the input resistor of the MPQ7731. Choose an input coupling capacitor such that the corner frequency ( $f_{IN}$ ) is less than the desired passband frequency.

The formula for the corner frequency is:

$$f_{IN} = \frac{1}{(2\pi RC)}$$

Where:

- R = R4 = R6
- C = C7 = C12

Where  $f_{IN}$  is the -3db cutoff frequency, R4 and R6 are the input resistors and C7 and C12 are the input AC coupling capacitors.

#### **Power Source**

For maximum output power, the amplifier circuit requires a regulated external power source to supply the power to the amplifier. The higher the power supply voltage, the more power can be delivered to a given load resistance. However, if the power source voltage exceeds the maximum operating voltage of 18V, the MPQ7731 may sustain damage. The power supply rejection of the MPQ7731 is excellent. However, noise at the power supply can get to the output, so care must be taken to minimize power supply noise within the pass-band frequencies. Bypass the power supply pins with a large electrolytic capacitor (typically aluminum electrolytic) along with smaller 1µF ceramic capacitors at the MPQ7731 V<sub>DD</sub> supply pins.

#### **Circuit Layout**

Proper circuit layout is critical for optimum performance and low output distortion and

noise. Place the following components as close to the MPQ7731 as possible:

- 1. Power Supply Bypass, C5, C11.
  - C5 and C11 carry the transient current for the switching power stage. Place a 1uF power supply bypass capacitor as close to Pin 18 (VDD1) and Pin 20 (PGND1) as possible. Also place a 1uF power supply bypass capacitor as close to Pin 13 (VDD2) and Pin 15 (PGND2) as possible.
- 2. **Output Catch Diodes, D2, D3, D5, and D6**. These diodes carry the current over the dead-time while both MOSFET switches are off. Place D3 between Pin 19 (SW1) and Pin 20 (PGND1) to prevent the voltage at SW1 from swinging excessively below ground, and place D2 between SW1 and pin 18 ( $V_{DD1}$ ) to prevent the voltage at SW1 from swinging excessively about  $V_{DD}$ . Place D6 and D5 similarly to minimize the undershoot and over-shoot of SW2 node.

#### 3. Input Modulator Capacitor, C10.

C10 is used to set the amplifier switching frequency. Place C10 as close to the differential inputs, Pin 2 and Pin 3, as possible to reduce distortion and noise.

#### Electro-Magnetic Interference (EMI)

Due to the switching nature of the Class-D amplifier, care must be taken to minimize the effects of electromagnetic interference from the amplifier. However, with proper component selection and careful attention to circuit layout, the effects of the EMI due to the amplifier switching can be minimized. The power inductors are a potential source of radiated emissions. For the best EMI performance, use shielded inductors, since the magnetic field is well contained inside the core. On the system printed circuit board, trace loops that carry rapidly changing currents need to be minimized. VDD bypass capacitors (C5 and C11) must be placed as close to the MPQ7731 as possible. Nodes that carry rapidly changing voltage, such as SW1 and SW2, must be made as small as possible. If sensitive traces run near SW1 or SW2, place a ground shield between the traces.



## **TYPICAL APPLICATION CIRCUIT**

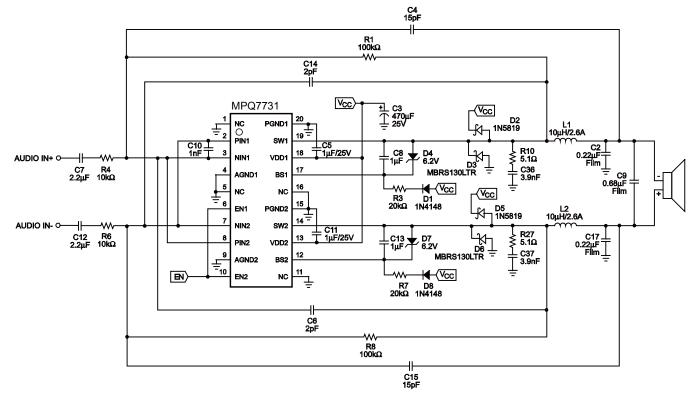
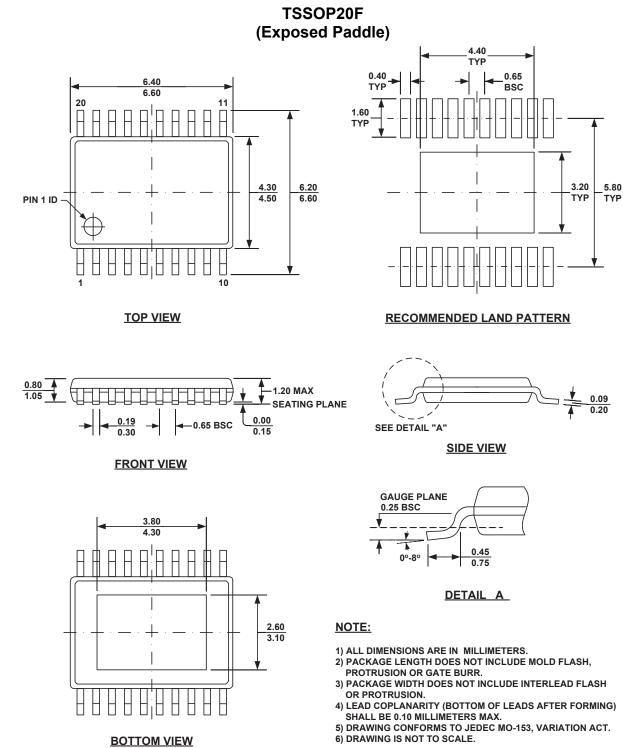


Figure 1— Mono Full Bridged Circuit



### **PACKAGE INFORMATION**



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